

L Number	Hits	Search Text	DB	Time stamp
1	2	("4975390" or ("5259247")).PN.	USPAT	2003/07/08 09:44
-	3	"9927325"	EPO; JPO; DERWENT	2003/07/08 09:44
-	1	1999-328283.NRAN.	DERWENT	2003/01/10 16:30
-	0	9927325.URPN.	USPAT	2003/01/10 16:31
-	0	thermal with membran with sensor	USPAT	2003/01/10 16:32
-	157	thermal with membrane with sensor	USPAT	2003/01/10 16:33
-	5	thermal near2 membrane near2 sensor	USPAT	2003/01/10 17:03
-	4	micromechanical near2 membrane near2 sensor	USPAT	2003/01/10 17:04
-	264	micromechanical near2 sensor	USPAT	2003/01/10 17:05
-	104641	silicon near2 (nitride carbide dioxide)	USPAT	2003/01/13 09:21
-	5612	(thermal or micromechanical) near2 sensor	USPAT	2003/01/12 11:54
-	1389	(428/156).CCLS.	USPAT	2003/01/12 11:54
-	619	(silicon near2 (nitride carbide dioxide)) and ((thermal or micromechanical) near2 sensor)	USPAT	2003/01/12 11:55
-	35645	428/\$3.\$2.ccls.	USPAT	2003/01/12 11:56
-	2	((silicon near2 (nitride carbide dioxide)) and ((thermal or micromechanical) near2 sensor)) and 428/\$3.\$2.ccls.	USPAT	2003/01/12 11:56
-	1	membrane near2 senor	USPAT	2003/01/13 09:20
-	1543	membrane near2 sensor	USPAT	2003/01/13 09:21
-	104641	silicon near2 (nitride carbide dioxide)	USPAT	2003/01/13 09:21
-	194	(membrane near2 sensor) and (silicon near2 (nitride carbide dioxide))	USPAT	2003/01/13 11:11
-	2	("5834334" or ("5712609")).PN.	USPAT	2003/01/15 10:58
-	438	counteracts with deformation	USPAT; US-PGPUB	2003/07/07 09:31
-	419082	sensor	USPAT; US-PGPUB	2003/07/07 09:31
-	364634	silicon	USPAT; US-PGPUB	2003/07/07 09:31
-	133535	(silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)	USPAT; US-PGPUB	2003/07/07 09:31
-	1026078	circuit	USPAT; US-PGPUB	2003/07/07 09:31
-	655	counteract\$5 with deformation	USPAT; US-PGPUB	2003/07/07 09:20
-	17	(counteract\$5 with deformation) and sensor and silicon	USPAT; US-PGPUB	2003/07/07 09:20
-	344561	deform\$5	USPAT; US-PGPUB	2003/07/07 09:30
-	419082	sensor	USPAT; US-PGPUB	2003/07/07 09:31
-	364634	silicon	USPAT; US-PGPUB	2003/07/07 09:31
-	133535	(silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)	USPAT; US-PGPUB	2003/07/07 09:31
-	205167	deformation	USPAT; US-PGPUB	2003/07/07 09:32
-	8785	(deform\$5 or deformation) and sensor and silicon	USPAT; US-PGPUB	2003/07/07 09:50
-	2952	((deform\$5 or deformation) and sensor and silicon) and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide))	USPAT; US-PGPUB	2003/07/07 09:33
-	31658	(deform\$5 or deformation) with (counteract or prevent)	USPAT; US-PGPUB	2003/07/07 10:43
-	211	((deform\$5 or deformation) with (counteract or prevent)) and sensor and silicon and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide))	USPAT; US-PGPUB	2003/07/07 10:43
-	17172	(deform\$5 or deformation) near3 (counteract or prevent)	USPAT; US-PGPUB	2003/07/07 10:43
-	116	((deform\$5 or deformation) near3 (counteract or prevent)) and sensor and silicon and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide))	USPAT; US-PGPUB	2003/07/07 11:35

-	0	((deform\$5 or deformation) near3 (counteract or prevent) and sensor and silicon and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide))) not (((deform\$5 or deformation) with (counteract or prevent)) and sensor and silicon and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)))	USPAT; US-PGPUB	2003/07/07 10:44
-	338	((deform\$5 or deformation) near3 (counteract or prevent) and sensor and silicon	USPAT; US-PGPUB	2003/07/07 10:45
-	222	((deform\$5 or deformation) near3 (counteract or prevent) and sensor and silicon) not (((deform\$5 or deformation) with (counteract or prevent)) and sensor and silicon and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)))	USPAT; US-PGPUB	2003/07/07 11:45
-	0	((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)) and 5259247.pn.	USPAT; US-PGPUB	2003/07/07 11:45
-	1	nitride and 5259247.pn.	USPAT; US-PGPUB	2003/07/07 12:56
-	7	5259247.URPN.	USPAT	2003/07/07 11:46
-	6	("3859575" "4507973" "4562742" "4719538" "4741214" "4951510").PN.	USPAT	2003/07/07 11:47
-	0	thickness and 5259247.pn.	USPAT; US-PGPUB	2003/07/07 11:51
-	430613	stabiliz\$5	USPAT; US-PGPUB	2003/07/07 12:57
-	841	(deform\$5 or deformation) and stabiliz\$5 and sensor and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide))	USPAT; US-PGPUB	2003/07/07 12:57
-	841	(deform\$5 or deformation) and stabiliz\$5 and sensor and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)) and silicon	USPAT; US-PGPUB	2003/07/07 13:09
-	39	((deform\$5 or deformation) same stabiliz\$5) and sensor and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)) and silicon	USPAT; US-PGPUB	2003/07/07 13:01
-	115	((deform\$5 or deformation) same stabiliz\$5) and sensor and silicon	USPAT; US-PGPUB	2003/07/07 13:01
-	76	((deform\$5 or deformation) same stabiliz\$5) and sensor and silicon) not (((deform\$5 or deformation) same stabiliz\$5) and sensor and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)) and silicon)	USPAT; US-PGPUB	2003/07/07 13:06
-	219	(361/283.1).CCLS.	USPAT	2003/07/07 13:06
-	70	(deform\$5 or deformation or stabiliz\$5) and ((361/283.1).CCLS.)	USPAT; US-PGPUB	2003/07/07 13:15
-	76829	pressure with sensor	USPAT; US-PGPUB	2003/07/07 13:14
-	2174	silicon and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)) and thickness and (pressure with sensor)	USPAT; US-PGPUB	2003/07/07 13:15
-	1008	(deform\$5 or deformation or stabiliz\$5) and (silicon and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)) and thickness and (pressure with sensor))	USPAT; US-PGPUB	2003/07/07 13:15
-	516	(stabiliz\$5) and (silicon and ((silicon near2 nitride) or (silicon near2 carbide) or (silicon near2 dioxide)) and thickness and (pressure with sensor))	USPAT; US-PGPUB	2003/07/07 14:24
-	1	4975390.pn. and (thickness or thick)	USPAT; US-PGPUB	2003/07/07 14:25